



### General Description

The AFE0514P is a 4-channel ultra low capacitance rail clamp ESD protection diodes array. Each channel consists of a pair of ESD diodes that steer positive or negative ESD current to either the positive or negative rail.

A zener diode is integrated in to the array between the positive and negative supply rails. In the typical applications, the negative rail pin (assigned as GND) is connected with system ground. The Positive ESD current is steered to the ground through an ESD diode and Zener diode and the positive ESD voltage is clamped to the zener voltage.

The AFE0514P is idea to protect high speed data lines.

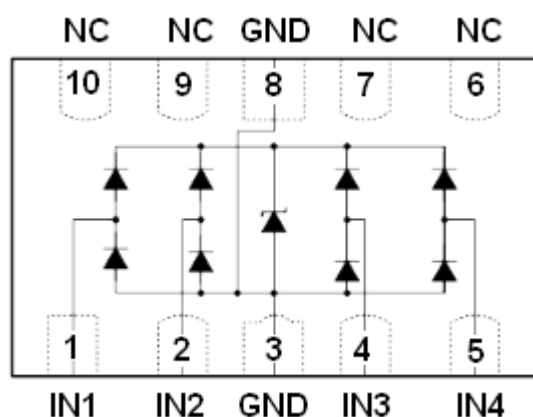
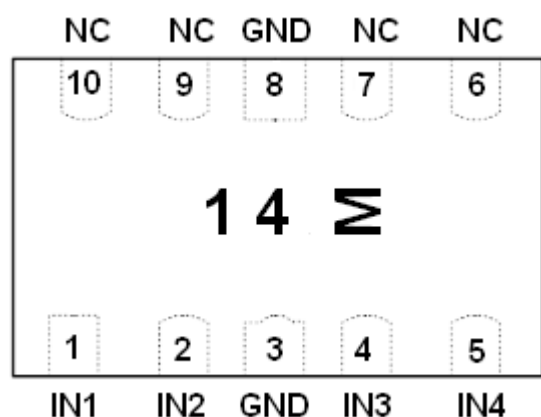
### Features

- 4 channels of ESD protection
- Provides ESD protection to IEC61000-4-2 level 4  $\pm 15$  KV air discharge  $\pm 8$  KV contact discharge
- Channel I/O to GND capacitance: 0.4pF(Max)
- Channel I/O to I/O capacitance: 0.25pF(Max)
- Low clamping voltage
- 5V low operating voltage
- Improved Zener structure
- Optimized package for easy high speed data lines PCB layout
- ROHS compliant

### Application

- High Definition Multi-Media Interface Protection
- USB 3.0 Power and Data Line Protection
- Monitors and Flat Panel Displays Notebook Computers
- Video Line Protection & Base Stations
- HDSL, IDSL Secondary IC Side Protection
- Microcontroller Input Protection
- LCD and camera modules
- 10/100/1000 Ethernet

### Pin Description Top View ( DFN-10 )



### Ordering Information

Part Ordering No.	Part Marking	Package	Unit	Quantity
AFE0514PFN10RG	14M	DFN-10	Tape & Reel	3000 EA

※ 14 Specific Device Code

※ M Month Code

※ AFE0514PFN10RG : 7" Tape & Reel ; Pb- Free ; Halogen- Free



**ABSOLUTE MAXIMUM RATINGS**

(T<sub>A</sub>=25°C Unless otherwise noted)

Parameter	Symbol	Typical	Unit
Peak Pulse Power ( t <sub>p</sub> = 8/20 μs )	P <sub>pk</sub>	150	W
Peak Pulse Current ( t <sub>p</sub> = 8/20 μs )	I <sub>PP</sub>	5	A
ESD per IEC 61000 – 4 – 2 (Air )	V <sub>ESD1</sub>	±15	KV
ESD per IEC 61000 – 4 – 2 (Contact )	V <sub>ESD2</sub>	±8	KV
Operating Junction Temperature	T <sub>J</sub>	-55 ~ 125	°C
Storage Temperature Range	T <sub>STG</sub>	-55 ~ 150	°C

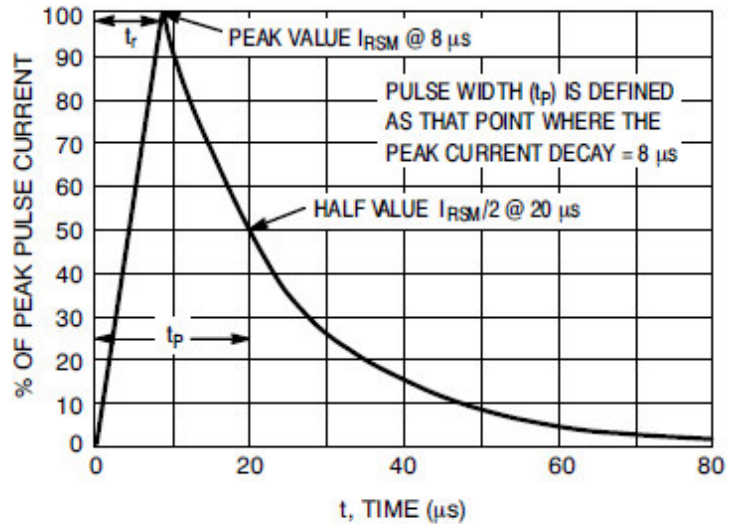
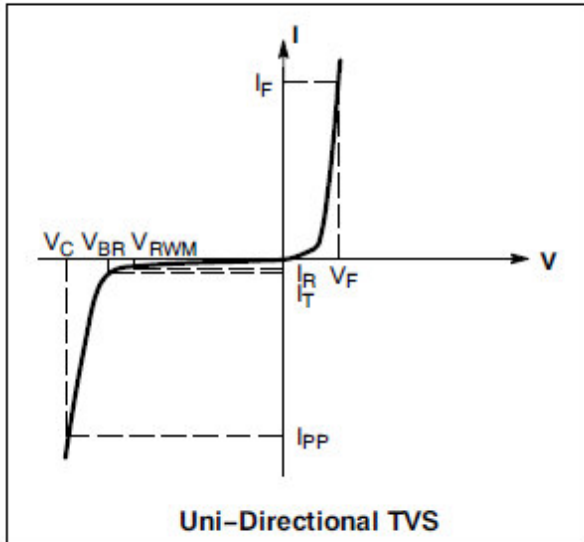
**ELECTRICAL CHARACTERISTICS**

(T<sub>A</sub>=25°C Unless otherwise noted)

Parameter	Symbol	Conditions	Min.	Typ	Max.	Unit
Reverse Working Voltage	V <sub>RWM</sub>	Any Pin to GND			5	V
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 10mA	0.4	0.8	1.5	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>t</sub> = 1mA Any Pin to GND	6	7		V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 5V , T=25°C Any Pin to GND		0.03	1	μA
Positive Clamping Voltage	V <sub>C1</sub>	I <sub>PP</sub> = 1A , t <sub>p</sub> = 8/20 μs Positive pulse Any Pin to GND		8.5	12	V
Negative Clamping Voltage	V <sub>C2</sub>	I <sub>PP</sub> = 1A , t <sub>p</sub> = 8/20 μs Negative pulse Any Pin to GND		1.8		V
Junction Capacitance Between Channel	C <sub>j1</sub>	V <sub>R</sub> = 0V , f = 1MHz Between I/O Pin		0.2	0.25	pF
Junction Capacitance Between I/O to GND	C <sub>j2</sub>	V <sub>R</sub> = 0V , f = 1MHz Any Pin to GND		0.35	0.4	pF



**Electrical Parameter**

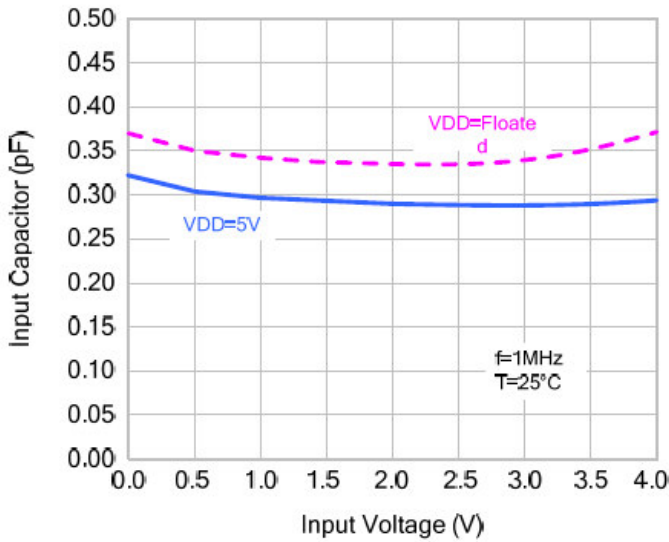


Symbol	Parameter
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{RWM}$	Working Peak Reverse Voltage
$I_R$	Maximum Reverse Leakage Current @ $V_{RWM}$
$I_T$	Test Current
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$

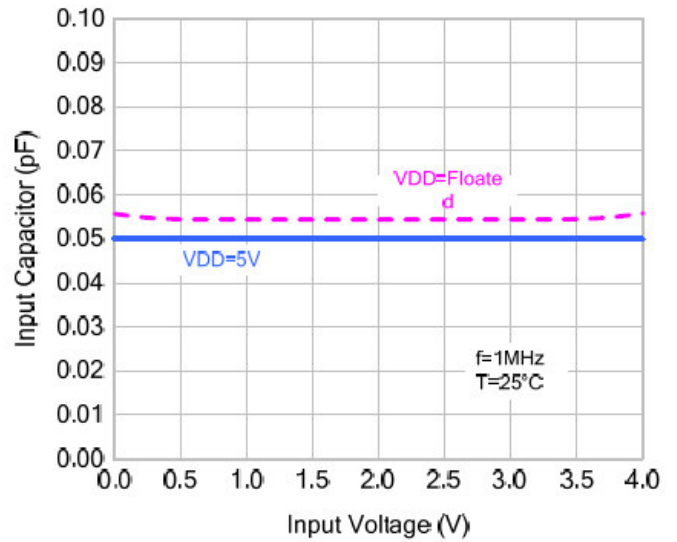


## Typical Characteristics

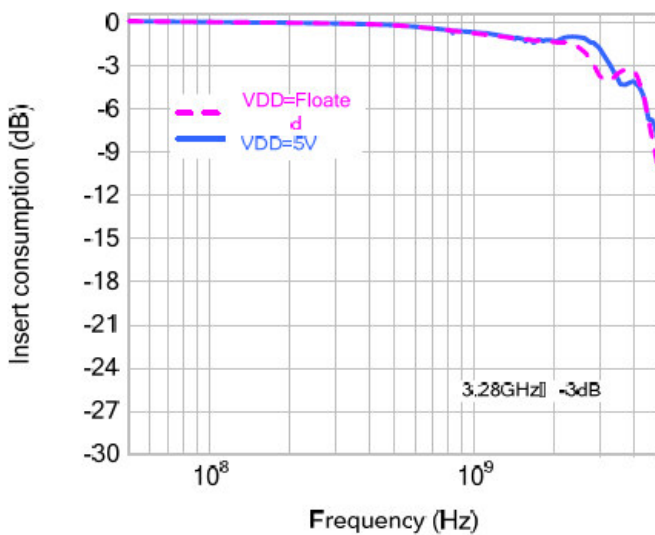
Typical curve of  $C_{IN}$  following  $V_{IN}$



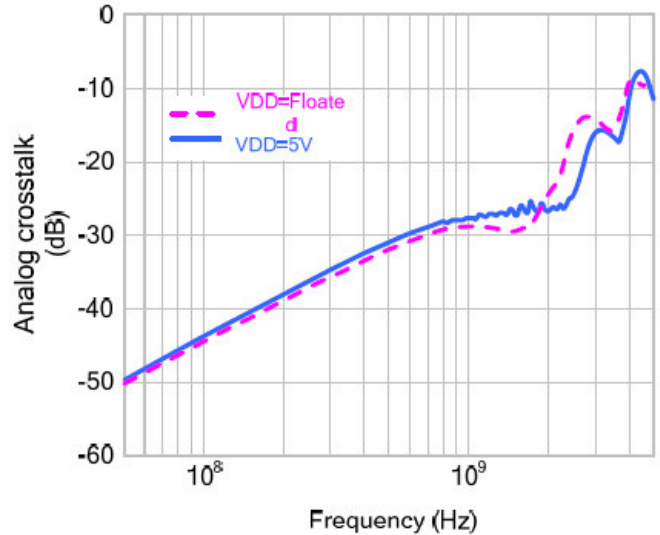
Typical curve of  $C_{I/O-to-I/O}$  following  $V_{IN}$



$S_{21}(I/O-to-GND)$

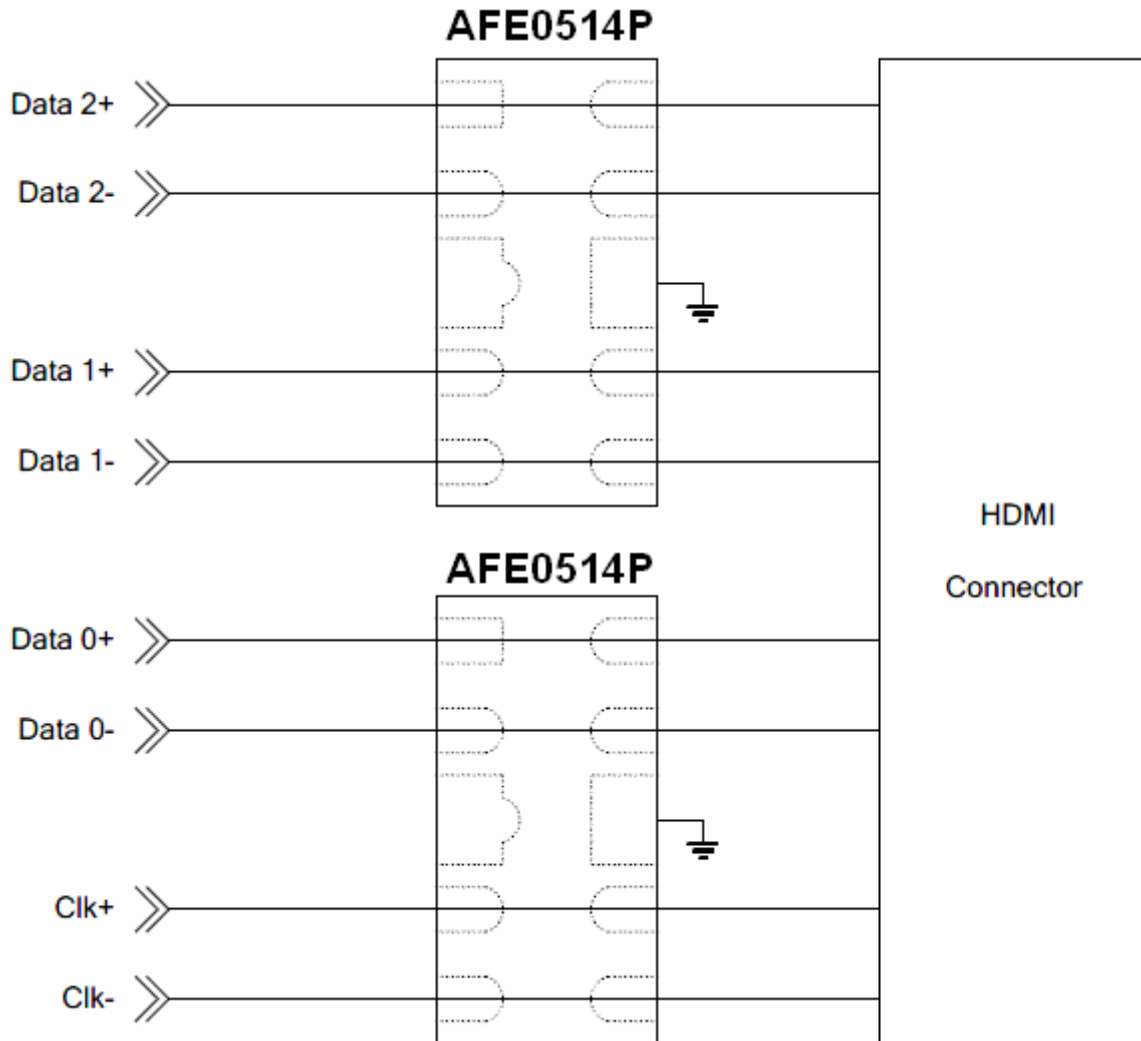


Analog crosstalk



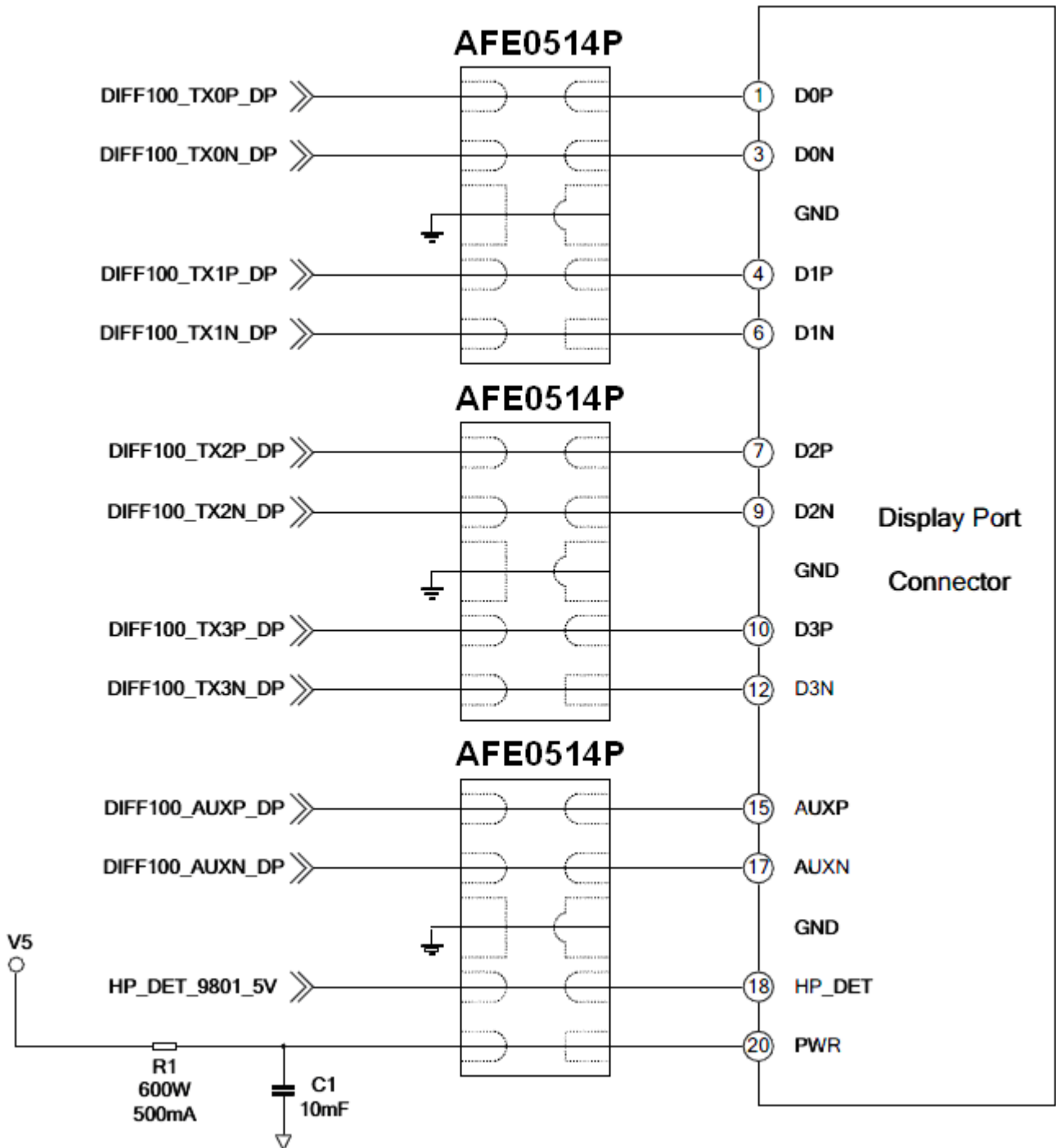


**Application Information**  
( HDMI Port Application )



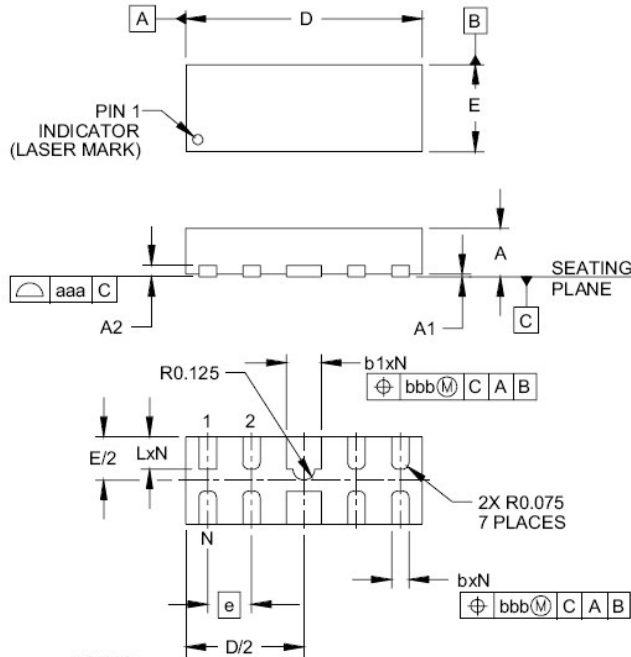


**Application Information**  
( Display Port Application )



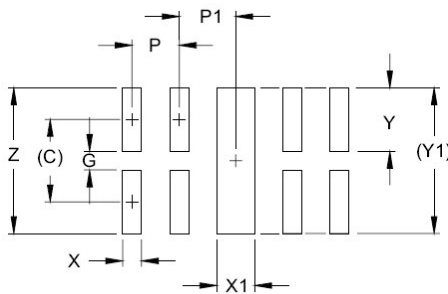


**Package Information ( DFN-10 )**



DIM	INCHES		MILLIMETERS			
	MIN	NOM	MAX	MIN	NOM	MAX
A	.020	.023	.026	0.50	0.58	0.65
A1	0.00	.001	.002	0.00	0.03	0.05
A2		(.005)			(0.13)	
b	.006	.008	.010	0.15	0.20	0.25
b1	.014	.016	.018	0.35	0.40	0.45
D	.094	.098	.102	2.40	2.50	2.60
E	.035	.039	.043	0.90	1.00	1.10
e		.020 BSC			0.50 BSC	
L	.012	.015	.017	0.30	0.38	0.425
N		10			10	
aaa		.003			0.08	
bbb		.004			0.10	

NOTES:  
1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).



DIM	DIMENSIONS	
	INCHES	MILLIMETERS
C	(.034)	(0.875)
G	.008	0.20
P	.020	0.50
P1	.020	0.50
X	.008	0.20
X1	.016	0.40
Y	.027	0.675
Y1	(.061)	(1.55)
Z	.061	1.55

NOTES:  
1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).  
2. THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY.  
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